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Romanov, C. M. Sotomayor Torres

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Micromoulding of three-dimensional photonic crystals on silicon substrates

P. Ferrand and M. J. Minty

Institute of Materials Science and Department of Electrical and Information Engineering,
University of Wuppertal, Gauss-Str. 20, D-42097 Wuppertal, Germany

M. Egen

Institute for Organic Chemistry, Department of Chemistry and Pharmacy, University of
Mainz, Duesbergweg 10-14, D-55099 Mainz, Germany

J. Ahopelto

VTT Centre for Microelectronics, P.O. Box 1208, FIN-02044 VTT, Finland

R. Zentel

Institute for Organic Chemistry, Department of Chemistry and Pharmacy, University of
Mainz, Duesbergweg 10-14, D-55099 Mainz, Germany

S. G. Romanov and C. M. Sotomayor Torres

Institute of Materials Science and Department of Electrical and Information Engineering,
University of Wuppertal, Gauss-Str. 20, D-42097 Wuppertal, Germany

The growth of three-dimensional photonic crystals (PhCs) on patterned silicon substrates is reported. It is shown that deep trenches can be uniformly filled by a self-assembly of polymer microspheres, in a close-packed face-centered cubic lattice. The crystalline quality is compared for different channel widths. These observations are confirmed by optical reflectance measurements in the visible range, showing a bandwidth of enhanced reflection. The possibility to detach the PhC, i.e., to use the substrate as a mould is also demonstrated. The potential of this approach for building complex PhC-based complex architectures is discussed.

42.70.Qs, 81.16.Dn, 42.70.Jk

Introduction

Photons interact with materials with a periodic variation of the index of refraction in a similar way to electrons with crystalline solids. Due to the improvement they provide in terms of emission control¹, guiding², as well as dispersion engineering³, the former called photonic crystals (PhCs) are expected to be elementary bricks of a future generation of opto-electronic devices of reduced size, combining high integration and high speed processing⁴. However, since a high refractive index contrast, as well as submicrometer feature sizes are required, the fabrication of such three-dimensional (3D) PhCs designed for the optical wavelengths is still a technological challenge.

In this context, much attention is paid to opals, i.e., photonic crystals made of close packed monodisperse microspheres⁵. Because their realisation is based on self-assembly,

the fabrication process is relatively cost-efficient, and can be extended to the large scale required by mass production. Moreover, the index contrast can be tailored by filling the voids between the balls⁶, and films of controlled thickness with single crystal domains of several mm² can be grown⁷. However, future functional devices will need complex PhC architectures, and therefore it is essential to be able to structure the crystal itself at the microscopic scale.

One way to achieve this goal is to control the crystal growth. The deposition can be electrically driven, using charged spheres and a locally charged substrate⁸, but this technique is limited to a few layers. Another promising way is the use of patterned substrates. Grooves⁹ or pits¹⁰ can trap spheres at predefined locations or, at larger scale, the growth of the PhC can be restricted in microscopic planar capillaries¹¹, or arbitrary complex deep structures¹².

In this article, our recent work on self-assembly of 3D PhC on deep etched structures in silicon wafers is reported. First the experimental details for preparation and characterisation of samples are given. Then the results of crystal growth in various geometries are presented, and these structural observations are complemented by optical measurements. The issue of cracks is discussed and the possibility to use them to detach the crystal from the substrate is demonstrated.

Experimental details

The (100) silicon wafers were etched in an inductively coupled plasma reactor, to typical etch depths between 7 and 10 μm . They were cleaned by a standard process, hydrophilised in a $\text{H}_2\text{O}_2(35\%):\text{NH}_3(25%):\text{H}_2\text{O}$ (1:1:5) bath for 3 hours, and rinsed in deionised water. The sedimentation was performed by drawing up the wafer in a vertical position with a velocity of about 300 nm/s from a 3 wt % suspension of monodisperse polymethylmethacrylate (PMMA) spheres of diameter 280 nm or 325 nm, prepared following the routine described elsewhere¹³. All processes were carried out at room temperature. Optical reflectance was measured using a Dilor XY 800 triple spectrometer equipped with a microscope, in a front white-light illumination configuration, through an intentionally low numerical aperture (0.25) objective ($\times 10$ magnification). Care was taken to use a spatial filter in order to select from the surface of the sample an effective area of $50 \times 50 \mu\text{m}^2$. Spectra were corrected by the response of the whole optical system. Prior to their observation by a Philips XL30 scanning electron microscope (SEM), the samples were sputtered with a thin film (10 nm) of gold.

Results and discussion

Control of growth

In order to obtain a film of uniform thickness, the PhC was grown in a vertical geometry⁷, as illustrated in Fig. 1a. Adjusting the lifting speed provided an additional control of the thickness^{14,15}, in order to match the trench depth. In addition, since the deposition of spheres takes place at the top of the meniscus^{14,16}, which is higher within the trenches due

to stronger capillary forces, the colloids are drained there and unetched silicon remains sparsely covered, as illustrated in Fig. 1b.

Structural properties

A SEM micrograph of a typical patterned substrate before the PhC growth is shown in Fig. 2a. Here the pattern is constituted by a set of 40- μm wide hexagons, etched to a depth of 7 μm . Hexagons have been chosen because their 120 degree angles match the crystallographic symmetry of the close package. Fig. 2b shows the sample after growth. Etched regions (appearing dark) are completely filled by 325 nm balls, and form a well-ordered 3D PhC of about 25 layers, whereas unetched regions (light) are just covered by one or two layers, as it can be seen in the close-up in Fig. 2c.

The filling takes place also in trenches narrower than 1 μm , as illustrated in Fig. 3. The ordering is relatively good and it can be seen on the bottom channel that the slight increase of width gives rise to a defect line, because it is no longer commensurable with the sphere size. The study of ordering as a function of depth is under current investigations. The main obstacle we have to overcome is the damage to the PhC when cleaving the sample.

Restricting us to the case of channels, the influence of the size on the structural properties has been also investigated. In Fig. 4a, a top view SEM micrograph of PhC in a 100- μm wide channel is shown. One can clearly see an almost perfect closed package of the 280 nm spheres, in a face-centred cubic (fcc) lattice of 396 nm lattice constant with the [111]

growth direction perpendicular to the surface of the substrate, similar to what is usually obtained on flat substrates. Fig. 4b shows a set of 10- μm wide channels. In this case, it is noticeable that the order is perturbed by some fluctuations of the lattice parameter.

Optical properties

These structural observations were complemented by absolute reflectance measurements carried out perpendicular to the sample surface, in regions illustrated in Fig. 4a and 4b, respectively. Both spectra in Fig. 5 show Fabry-Perot interference fringes as a evidence for the uniform total optical thickness of the PhC, and a Bragg reflection at wavelengths around 620 nm, as a proof of the periodic nature of the PhC. The wavelength of the Bragg reflection and the relative bandwidth $\Delta\lambda/\lambda = 5.5\%$ in the wide channel case (Fig. 5, thick line), are in good agreement with the theoretical estimate of the stop-band along the [111] direction for PMMA spheres of refractive index $n = 1.489$, close-packed in a fcc lattice (filling fraction 74%)¹⁷. The Bragg peak of the sample grown on the narrow channel (Fig. 4b) appears less intense and slightly broader (Fig. 5, thin line, $\Delta\lambda/\lambda = 8.5\%$). This is a consequence of the slight disorder mentioned above, which takes place both in the plane and in depth. At the moment, the reasons for this remain unclear and are under investigation.

Issue of cracks

Finally, it is observed that the location of cracks is also strongly affected by the finite trench size. Indeed, these cracks are probably a consequence of strains induced by the shrinkage of the colloidal crystal¹⁸. In the case of opal grown on an unpatterned substrate

or in a wide trench, these cracks are almost randomly distributed over the surface. Nevertheless, a typical size of crack-free domains can be empirically predicted. In our specific case, Fig. 4a shows that this size is about a couple of hundred square micrometers. The patterned substrate is in practice a rigid frame, which, for trenches smaller than the crack-free typical size, gives rise to large strains. This results in cracks appearing only at the opal-substrate interfaces. This gives a guarantee of a structure free of cracks, at least in volume. This is clearly visible in Fig. 2b, where cracks are located along side walls.

Detached structures

Moreover, more than defects, these cracks are of practical interest, since they are not exclusively located along side walls but also at the bottom interface. They can be used to detach the opal structure from the substrate¹². For this purpose, an adhesive tape was placed on the sample surface, and carefully released as illustrated in Figs. 6a and 6b. A top view SEM micrograph of the detached structure is shown in Fig. 7. The result resembles an elongated brick, of cross section about of $10 \times 10 \mu\text{m}^2$, showing a straight edge and flat sides. The order seen on the top side corresponds to the early stage of the crystallisation, occurring at the bottom of the trench. This provides a further proof of the good global crystalline quality of the sample. The slight damage at the top edge of the crystal is due to the crude process used in this first attempt.

This approach, using the substrate as a mould and releasing the PhC after sedimentation, is a promising way to overcome some measurement challenges of 3D PhCs. For instance,

detached structures can be investigated from the lateral sides, e.g., in and out-coupling for waveguide measurements, without requiring sawing and polishing. Moreover, by suspending the crystal, emission studies avoiding the critical influence of the substrate will be possible. Lastly, this technique may allow the construction of multilayer circuits, as in microelectronics. In our case, the construction would need two steps. i) Crystallization of each PhC circuit layer separately, using the structured Si substrates as a mould and ii) unmoulding and stacking. Figure 6c illustrates an example of complex PhC multilayer architecture, which could be realized by means of this process.

Conclusion

In summary, 3D PhC moulding using deeply etched silicon wafers has been reported. SEM observations showed a uniform filling of the trenches, as well as a close-packed ordering in a fcc lattice. These observations were confirmed by optical measurements, showing Fabry-Perot fringes as well as a Bragg reflection, the spectral position and width of which agreed with theoretical calculations. A slight disorder was observed in the case of the narrowest trenches. It was noticed that cracks occur preferably close the PhC-substrate interface, giving the possibility to detach the structure from the substrate.

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FIGURES

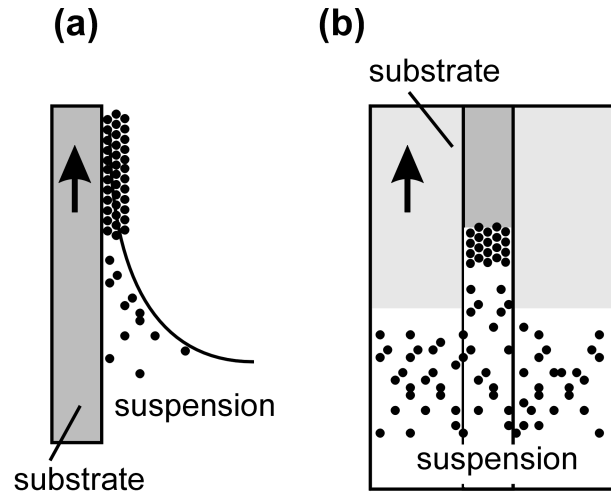


Fig. 1. (a) Schematic view of the geometry used for the PhC growth (side view).

Capillary forces drive spheres to the top on the meniscus. The film thickness is controlled by the concentration of the suspension, as well as by the lifting speed. (b) Case of a patterned substrate. Balls are drained into the trenches because the meniscus is higher.

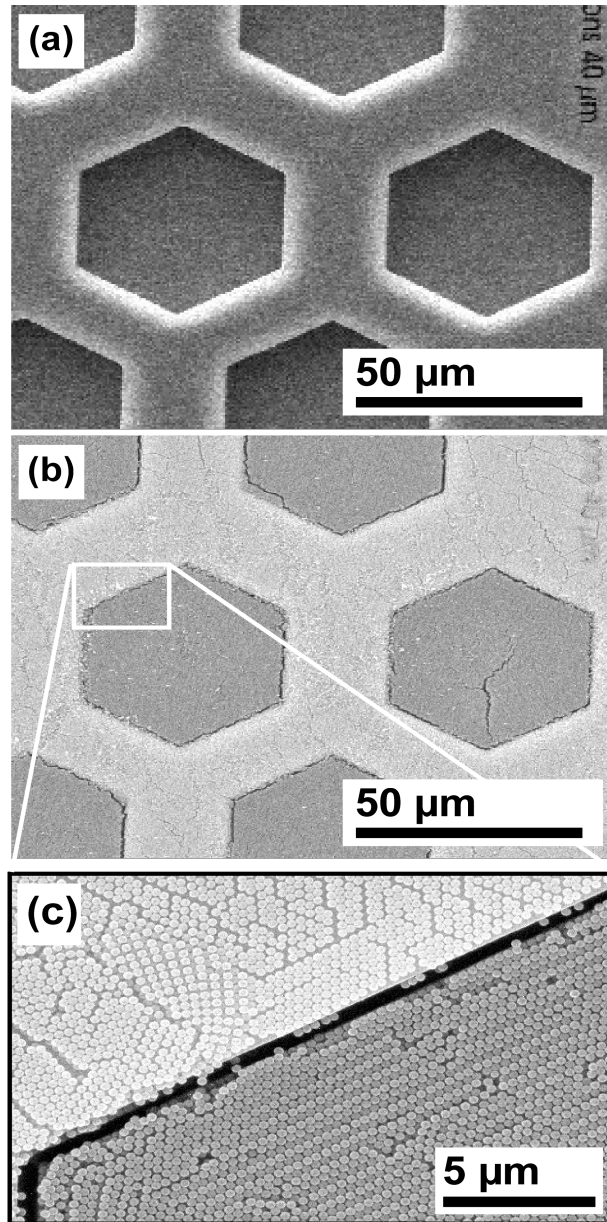


Fig. 2. (a) Top view SEM micrograph of a patterned substrate prior to the PhC growth. Etch depth is 7 μm . (b) Same view after growth. A 7- μm thick PhC fills dark regions, whereas light regions are just covered by one or two layers. (c) Close-up.

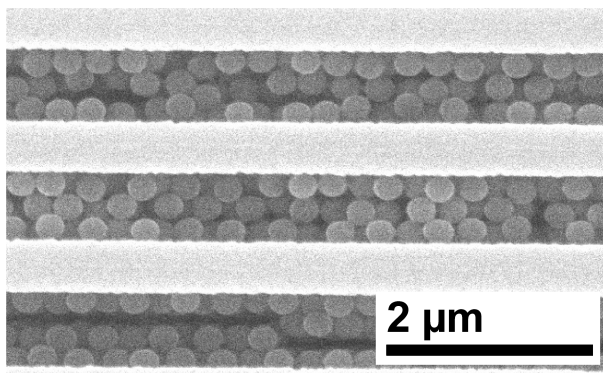


Fig. 3. Top view SEM micrograph showing that the PhC has grown even in narrow channels (less than 1 μm). Note that bottom channel is slightly wider.

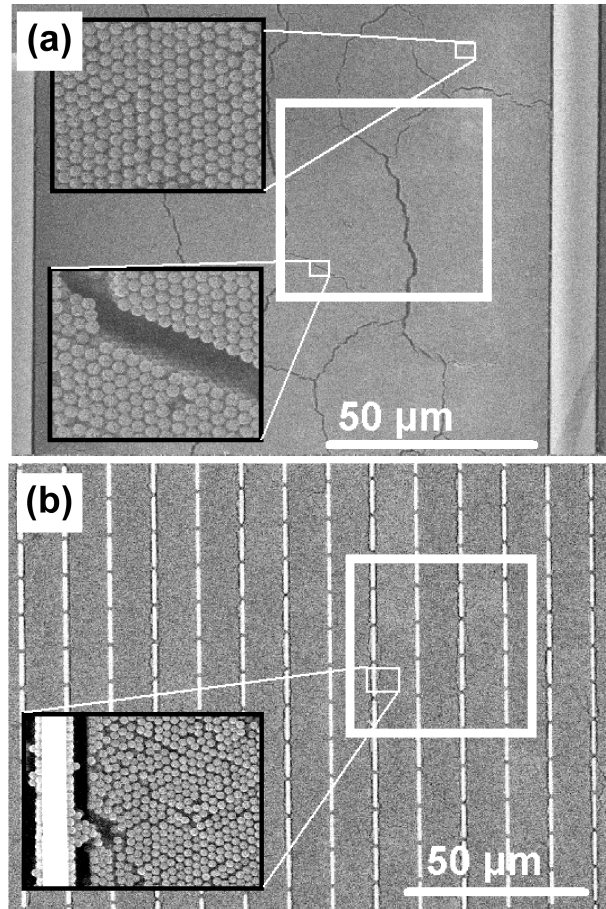


Fig. 4. Top view SEM micrographs showing the influence of the trench width on the crystal ordering. (a) Wide case (100 μm). (b) Set of narrower (10 μm) trenches. Insets are close-ups.

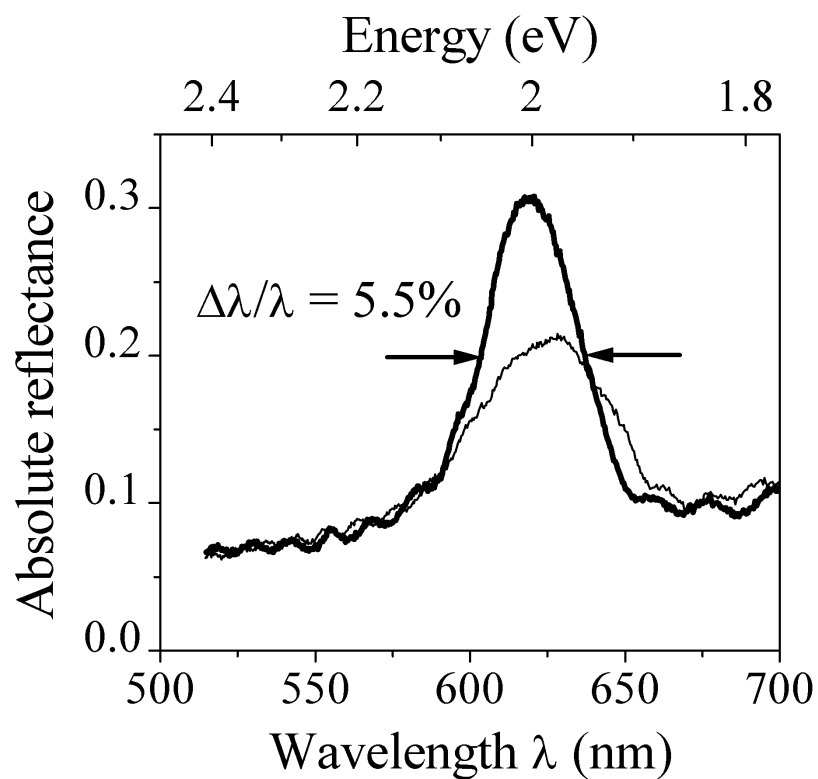


Fig. 5. Normal incidence absolute reflectance spectra, measured in regions indicated in white squares in Figs. 4a (thick line) and 4b (thin line).

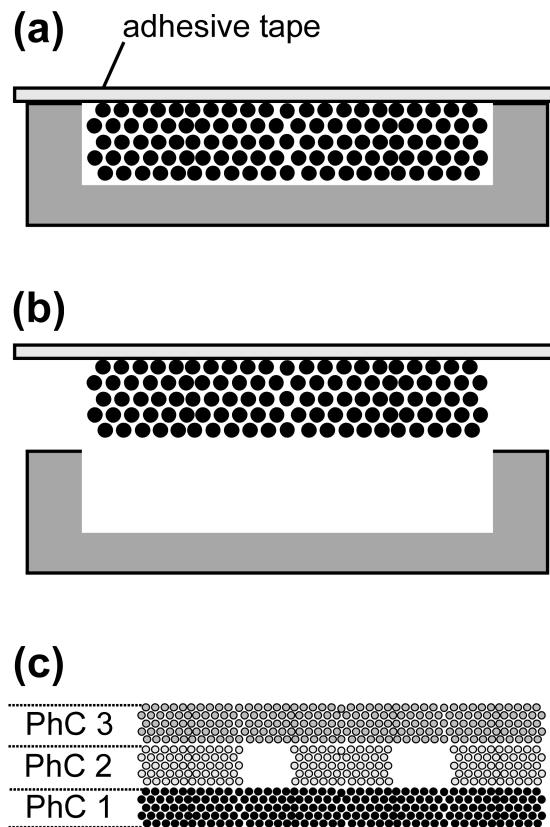


Fig. 6. Scheme illustrating the technique to detach the PhC from the substrate. (a) Step 1: An adhesive tape is moderately pressed on the sample. (b) Step 2 : The PhC is released carefully. (c) Example (side view) of a complex PhC architecture that could be realized by stacking several pre-moulded PhCs (called here PhC1, etc.)

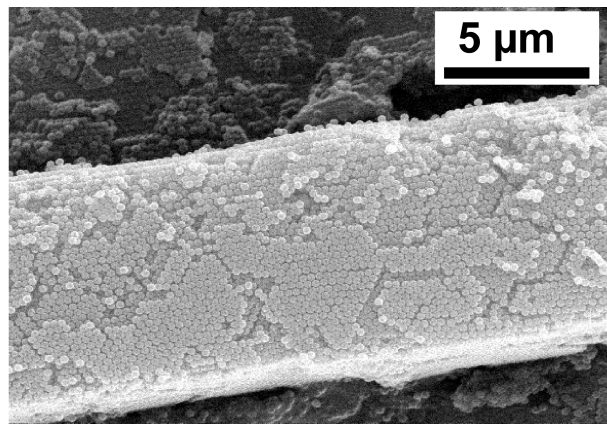


Fig. 7. Top view SEM micrograph of the detached structure.

REFERENCES

- ¹ E. Yablonovitch, *Phys. Rev. Lett.* **58**, 2059 (1987).
- ² A. Mekis, J. C. Chen, I. Kurland, S. Fan, P. R. Villeneuve and J. D. Joannopoulos, *Phys. Rev. Lett.* **77**, 3787 (1996).
- ³ B. Gralak, S. Enoch and G. Tayeb, *J. Opt. Soc. Am. A* **17**, 1012 (2000).
- ⁴ J. D. Joannopoulos, P. R. Villeneuve and S. Fan, *Nature* **386**, 143 (1997).
- ⁵ V. N. Astratov, V. M. Bogomolov, A. A. Kaplyanskii, A. V. Prokofiev, L. A. Samoilovich, S. M. Samoilovich and Y. A. Vlasov, *Nuovo Cimento* **17D**, 1349 (1995).
- ⁶ Y. A. Vlasov, X. Z. Bo, J. C. Sturm, and D. J. Norris, *Nature* **414**, 289 (2001).
- ⁷ P. Jiang, J. F. Bertone, K. S. Hwang and V. L. Colvin, *Chem. Mater.* **11**, 2132 (1999).
- ⁸ E. Kumacheva, R. K. Golding, M. Allard and E. H. Sargent, *Adv. Mater.* **14**, 221 (2002).
- ⁹ Y. H. Ye, S. Badilescu, V. V. Truong, P. Rochon and A. Natasohn, *Appl. Phys. Lett.* **79**, 872 (2001).
- ¹⁰ G. A. Ozin and S. M. Yang, *Adv. Funct. Mater.* **11**, 95 (2001) ; Y. Yin and Y. Xia, *Adv. Mater.* **14**, 605 (2002).
- ¹¹ S. M. Yang, H. Míguez and G. A. Ozin, *Adv. Funct. Mater.* **12**, 425 (2002).
- ¹² P. Ferrand, M. Egen., B. Griesebock, J. Ahopelto, M. Müller, R. Zentel, S. G. Romanov and C. M. Sotomayor Torres, *Appl. Phys. Lett.* **81**, 2689 (2002).
- ¹³ M. Müller, R. Zentel, T. Maka, S. G. Romanov and C. M. Sotomayor Torres ,

Chem. Mater. **12**, 2508 (2000).

¹⁴ Z. Z. Gu, A. Fujishima and O. Sato, *Chem. Mater.* **14**, 760 (2002).

¹⁵ M. Egen, B. Griesebock, R. Zentel, P. Ferrand, S. G. Romanov and C. M. Sotomayor Torres, *unpublished*.

¹⁶ J. Aizenberg, P. V. Braun and P. Wiltzius, *Phys. Rev. Lett.* **84**, 2997 (2000).

¹⁷ S. G. Romanov, T. Maka, C. M. Sotomayor Torres, M. Müller, R. Zentel, D.

Cassagne, J. Manzanares-Martinez and C. Jouanin, *Phys. Rev. E* **63**, 056603 (2001).

¹⁸ B. Griesebock, M. Egen, and R. Zentel, *Chem. Mater.* **14**, 4023 (2002).